

CLAIMS

- 1    1. An immersion lithographic system for patterning a work piece arranged at an image plane  
2        and covered at least partly with a layer sensitive to electromagnetic radiation, comprising:  
3           - a source emitting electromagnetic radiation onto an object plane,  
4           - a modulator, adapted to receive and modulate said electromagnetic radiation at said object  
5        plane in accordance to an input pattern description, and to relay said electromagnetic  
6        radiation toward said work piece,  
7           - an immersion medium contacting at least a portion of an immersion optics of said  
8        lithographic system and a portion of said work piece, wherein said immersion medium is  
9        supplied through at least one orifice arranged in said immersion optic.
  
- 1    2. The apparatus according to claim 1, wherein said modulator is an SLM.
  
- 1    3. The apparatus according to claim 2, wherein said SLM comprises reflective pixels.
  
- 1    4. The apparatus according to claim 3, wherein said reflective pixels are micromirrors.
  
- 1    5. The apparatus according to claim 1, wherein said modulator is a acoustooptical  
2        modulator.
  
- 1    6. The apparatus according to claim 1, wherein said source emitting electromagnetic  
2        radiation is an excimer laser.
  
- 1    7. The apparatus according to claim 1, further comprising a porous or fibrous material  
2        through which said immersion medium is supplied.
  
- 1    8. The apparatus according to claim 1, further comprising at least one immersion medium  
2        removal orifice.
  
- 1    9. The apparatus according to claim 8, further comprising a porous or fibrous material  
2        through which said immersion medium is removed.

- 1    10. The apparatus according to claim 7 or 9, wherein said at porous material is kept
- 2       incompletely saturated with said immersion medium.
  
- 1    11. An immersion lithographic system for patterning a work piece arranged at an image
- 2       plane and covered at least partly with a layer sensitive to electromagnetic radiation,
- 3       comprising
  - 4       - a source emitting electromagnetic radiation onto an object plane,
  - 5       - a mask arranged at said object plane to relay said electromagnetic radiation toward said
  - 6       work piece,
  - 7       - an immersion medium contacting at least a portion of an immersion optics of said
  - 8       lithographic system and a portion of said work piece, wherein said immersion medium is
  - 9       supplied through at least one orifice arranged in said immersion optics.
  
- 1    12. The apparatus according to claim 11, wherein said source emitting electromagnetic
- 2       radiation is an excimer laser.
  
- 1    13. The apparatus according to claim 11, further comprising a porous or fibrous material
- 2       through which said immersion medium is supplied.
  
- 1    14. The apparatus according to claim 11, further comprising at least one immersion medium
- 2       removal orifice.
  
- 1    15. The apparatus according to claim 14, further comprising a porous or fibrous material
- 2       through which said immersion medium is removed.
  
- 1    16. The apparatus according to claim 13 or 15, wherein said at porous or fibrous material is
- 2       kept incompletely saturated with said immersion medium.
  
- 1    17. An immersion lithographic system for patterning a work piece arranged at an image plane
- 2       and covered at least partly with a layer sensitive to electromagnetic radiation, comprising
  - 3       - a source emitting electromagnetic radiation onto an object plane,

- 4    - a modulator, adapted to receive and modulate said electromagnetic radiation at said object  
5    plane in accordance to an input pattern description and to relay said electromagnetic  
6    radiation toward said work piece,
- 7    - an immersion medium contacting at least a portion of a objective lens of said lithographic  
8    system and a portion of said work piece, wherein an area of said contacting is restricted by  
9    capillary forces.

1    18. The immersion lithography system according to claim 17, further comprising a  
2    immersion medium reservoir for supplying immersion medium to said portion of said  
3    objective lens and said workpiece.

1    19. The immersion lithography system according to claim 18, wherein said immersion  
2    medium is supplied through a porous or fibrous material.

1    20. An immersion lithographic system for patterning a work piece arranged at an image plane  
2    and covered at least partly with a layer sensitive to electromagnetic radiation, comprising  
3    - a source emitting electromagnetic radiation onto an object plane,  
4    - a mask, adapted to receive and modulate said electromagnetic radiation at said object  
5    plane and to relay said electromagnetic radiation toward said work piece,  
6    - an immersion medium contacting at least a portion of a final lens of said lithographic  
7    system and a portion of said work piece, wherein an area of said contacting is restricted by  
8    capillary forces.

1    21. The immersion lithography system according to claim 17, further comprising a  
2    immersion medium reservoir for supplying immersion medium to said portion of said  
3    objective lens and said workpiece.

1    22. The immersion lithography system according to claim 18, wherein said immersion  
2    medium is supplied through a porous or fibrous material.

1    23. A method for patterning a workpiece arranged at an image plane and covered at least  
2    partly with a layer sensitive to electromagnetic radiation, including the actions of:  
3    - emitting electromagnetic radiation onto an object plane,

4 - modulating said electromagnetic radiation at said object plane in accordance to an input  
5 pattern description,  
6 - relaying said electromagnetic radiation toward said workpiece,  
7 - supplying an immersion medium to contact at least a portion of an objective lens of said  
8 lithographic system and at least a portion of said workpiece.

1 24. The method according to claim 23, further comprising the action of:

2 - restricting a lateral extension of said contact by capillary forces.

1 25. A method for patterning a workpiece arranged at an image plane and covered at least  
2 partly with a layer sensitive to electromagnetic radiation, including the actions of:

3 - emitting electromagnetic radiation onto an object plane,  
4 - modulating said electromagnetic radiation at said object plane in accordance to an input  
5 pattern description,  
6 - relaying said electromagnetic radiation toward said workpiece,  
7 - contacting at least a portion of an objective lens of said lithographic system and at least a  
8 portion of said workpiece via a immersion medium, wherein said contacting is restricted  
9 in a lateral direction of said workpiece by capillary forces.

1 26. The method according to claim 25, further including the action of:

2 - supplying said immersion medium via a immersion medium reservoir.

1 27. The method according to claim 26, wherein said immersion medium is supplied through  
2 a porous or fibrous material.

1 28. A method for patterning a workpiece arranged at an image plane and covered at least  
2 partly with a layer sensitive to electromagnetic radiation, including the actions of:  
3 - emitting electromagnetic radiation onto an object plane,  
4 - modulating said electromagnetic radiation at said object plane in accordance to an input  
5 pattern description,  
6 - relaying said electromagnetic radiation toward said workpiece,  
7 - forming an immersion medium film to contact at least a portion of an objective lens of  
8 said lithographic system and at least a portion of said workpiece,

MLSE 1035-1

- 9    - supplying immersion medium to said immersion medium film to maintain its lateral
- 10    dimensions while moving said objective lens over said workpiece.